

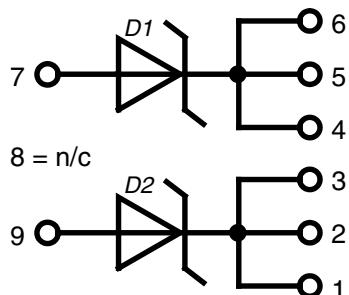
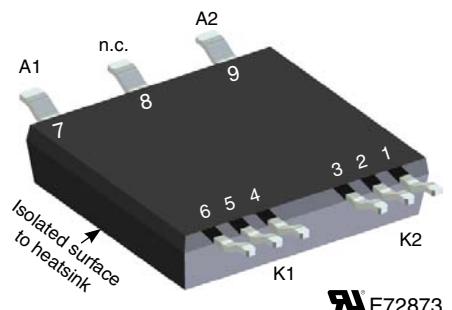
Schottky Diode Gen²

V_{RRM} = 200 V
I_{DAV} = 2x 65 A
V_F = 0.67 V

High Performance Schottky Diode
Low Loss and Soft Recovery
Parallel Legs

Part number
DSA120X200LB

Preliminary data



Features / Advantages:

- Very low V_F
- Extremely low switching losses
- Low I_{RM} values
- Improved thermal behaviour
- High reliability circuits operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

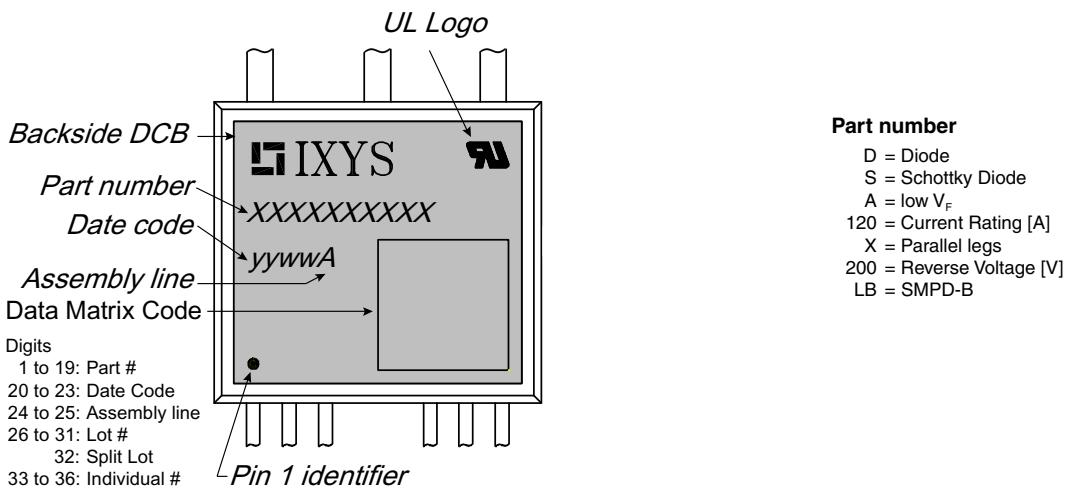
- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: SMPD

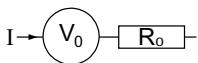
- Isolation Voltage: 3000 V~ (t = 1s)
- Industry convenient outline
- RoHS compliant
- Soldering pins for PCB mounting
- Backside: DCB ceramic
- Reduced weight
- Advanced power cycling

Schottky			Ratings		
Symbol	Definitions	Conditions	min.	typ.	max.
V_{RSM}	max. non-repetitive rev. blocking voltage	$T_{VJ} = 25^\circ\text{C}$			200 V
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			200 V
I_R	reverse current, drain current	$V_R = 200 \text{ V}$ $T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$			1 mA 5 mA
V_F	forward voltage drop	$I_F = 60 \text{ A}$ $I_F = 120 \text{ A}$ $T_{VJ} = 25^\circ\text{C}$ $I_F = 60 \text{ A}$ $I_F = 120 \text{ A}$ $T_{VJ} = 150^\circ\text{C}$			0.98 V 1.22 V 0.82 V 1.10 V
I_{FAV}	average forward current	rectangular; $d = 0.5$	$T_C = 130^\circ\text{C}$		65 A
V_{FO} r_F	threshold voltage slope resistance	for power loss calculation only	$T_{VJ} = 175^\circ\text{C}$		0.51 V 2.7 mΩ
R_{thJC}	thermal resistance junction to case				0.8 K/W
R_{thJH}	thermal resistance case to heatsink	with thermal transfer paste (IXYS test setup)		1.05	1.25 K/W
P_{tot}	total power dissipation		$T_C = 25^\circ\text{C}$		185 W
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 \text{ V}$	$T_{VJ} = 45^\circ\text{C}$		700 A
C_J		$V_R = 24 \text{ V}; f = 1 \text{ MHz}$	$T_{VJ} = 25^\circ\text{C}$		395 pF

Package SMPD			Ratings		
Symbol	Definitions	Conditions	min.	typ.	max.
I_{RMS}	RMS current	wide pin standard pin		100 60	A A
T_{stg}	storage temperature		-55	150	°C
T_{op}	operation temperature		-55	150	°C
T_{VJ}	virtual junction temperature		-55	175	°C
Weight				8.5	g
F_c	mounting force with clip		40	130	N
$d_{Spp/App}$	creepage distance on surface /	terminal to terminal	1.6		mm
$d_{Spb/App}$	striking distance through air	terminal to backside	4.0		mm
V_{ISOL}	isolation voltage	$t = 1$ second $t = 1$ minute	50/60 Hz; RMS; $I_{ISOL} < 1$ mA	3000 2500	V V



Ordering	Part Name	Marking on Product	Delivering Mode	Base Qty	Ordering Code
Standard	DSA120X200LB-TRR	DSA120X200LB-TRR	Tape&Reel	200	
	DSA120X200LB	DSA120X200LB	Blister	45	512873

Equivalent Circuits for Simulation *on die level $T_{VJ} = 175^\circ\text{C}$


Schottky

$V_{0\ max}$ threshold voltage 0.51 V
 $R_{0\ max}$ slope resistance * 2.7 mΩ

Outlines SMPD

A (8 : 1)

